NSN 5961-01-456-5058



Transistor - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5961-01-456-5058 **Inclosure Material:** Metal and ceramic **Overall Length:** Between 0.790 inches and 0.800 inches **Overall Height:** Between 0.249 inches and 0.260 inches **Overall Width:** Between 0.535 inches and 0.545 inches **Mounting Facility Quantity: Internal Configuration:** Field effect Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-254aa **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 200.0 breakdown voltage, drain-to-source, with all other terminals short-circuited to source and 20.0 gate to source voltage **Current Rating Per Characteristic:** 18.00 amperes drain current and 18.00 amperes source current **Power Rating Per Characteristic:** 125.0 watts total power dissipation **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Test Data Document:** 81349-mil-prf-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 3 pin **Specification Data:**

81349-mil-prf-19500/596 government specification

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0

Mil-std (military Standard):

Mil-prf-19500 spec.